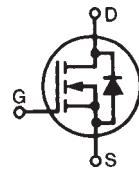
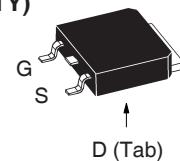
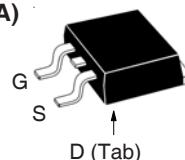
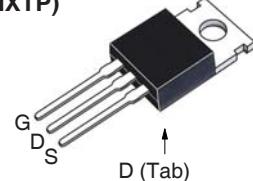


**TrenchT2™  
Power MOSFET**
**IXTY90N055T2  
IXTA90N055T2  
IXTP90N055T2**
 **$V_{DSS}$  = 55V  
 $I_{D25}$  = 90A  
 $R_{DS(on)}$  ≤ 8.4mΩ**
**N-Channel Enhancement Mode  
Avalanche Rated**

**TO-252 (IXTY)**

**TO-263 (IXTA)**

**TO-220 (IXTP)**


G = Gate      D = Drain  
S = Source      Tab = Drain

Symbol	Test Conditions	Maximum Ratings	
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$	55	V
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$ , $R_{GS} = 1\text{M}\Omega$	55	V
$V_{GSM}$	Transient	±20	V
$I_{D25}$	$T_c = 25^\circ\text{C}$	90	A
$I_{DM}$	$T_c = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$	230	A
$I_A$	$T_c = 25^\circ\text{C}$	50	A
$E_{AS}$	$T_c = 25^\circ\text{C}$	300	mJ
$P_D$	$T_c = 25^\circ\text{C}$	150	W
$T_J$		-55 ... +175	°C
$T_{JM}$		175	°C
$T_{stg}$		-55 ... +175	°C
$T_L$	Maximum Lead Temperature for Soldering	300	°C
$T_{SOLD}$	1.6 mm (0.062in.) from Case for 10s	260	°C
$F_c$	Mounting Force (TO-263)	10..65 / 2.2..14.6	N/lb
$M_d$	Mounting Torque (TO-220)	1.13 / 10	Nm/lb.in
<b>Weight</b>	TO-252	0.35	g
	TO-263	2.50	g
	TO-220	3.00	g

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{DSS}$	$V_{GS} = 0\text{V}$ , $I_D = 250\mu\text{A}$	55		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\mu\text{A}$	2.0		4.0 V
$I_{GSS}$	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$			±200 nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ , $V_{GS} = 0\text{V}$ $T_J = 150^\circ\text{C}$			2 μA 200 μA
$R_{DS(on)}$	$V_{GS} = 10\text{V}$ , $I_D = 25\text{A}$ , Notes 1 & 2	7.0		8.4 mΩ

**Features**

- International Standard Packages
- Avalanche Rated
- Low Package Inductance
- Fast Intrinsic Rectifier
- 175°C Operating Temperature
- High Current Handling Capability
- ROHS Compliant
- High Performance Trench
- Technology for extremely low  $R_{DS(on)}$

**Advantages**

- High Power Density
- Easy to Mount
- Space Savings

**Applications**

- Automotive Engine Control
- Synchronous Buck Converter (for Notebook SystemPower & General Purpose Point & Load)
- DC/DC Converters
- High Current Switching Applications
- Power Train Management
- Distributed Power Architecture

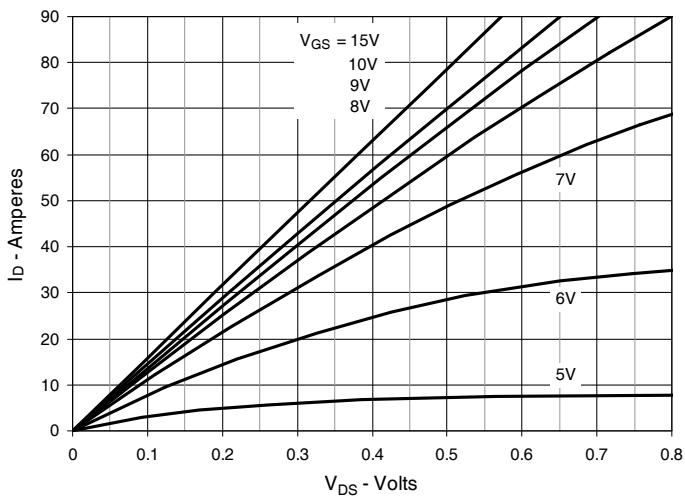
Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$V_{DS} = 10\text{V}$ , $I_D = 45\text{A}$ , Note 1	25	43	S
$C_{iss}$	$V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$	2770	pF	
$C_{oss}$		420	pF	
$C_{rss}$		102	pF	
$t_{d(on)}$	<b>Resistive Switching Times</b> $V_{GS} = 10\text{V}$ , $V_{DS} = 30\text{V}$ , $I_D = 25\text{A}$ $R_G = 5\Omega$ (External)	19	ns	
$t_r$		21	ns	
$t_{d(off)}$		39	ns	
$t_f$		19	ns	
$Q_{g(on)}$	$V_{GS} = 10\text{V}$ , $V_{DS} = 30\text{V}$ , $I_D = 25\text{A}$	42	nC	
$Q_{gs}$		14	nC	
$Q_{gd}$		8.5	nC	
$R_{thJC}$	TO-220		1.00 $^\circ\text{C}/\text{W}$	
$R_{thCS}$		0.50	$^\circ\text{C}/\text{W}$	

### Source-Drain Diode

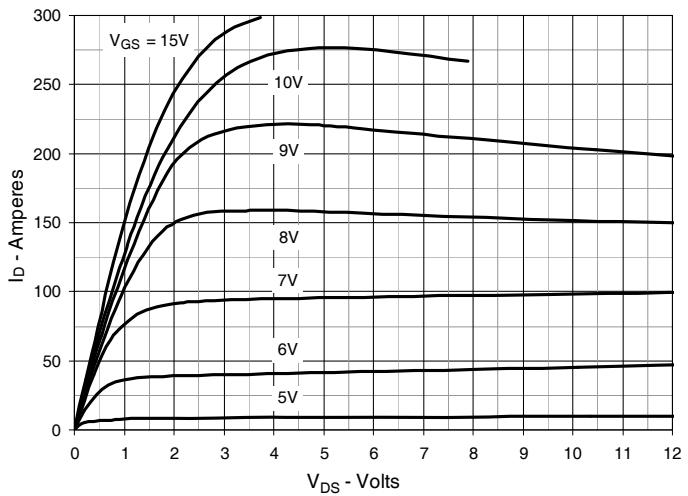
Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$I_s$	$V_{GS} = 0\text{V}$		90	A
$I_{SM}$	Repetitive, Pulse Width Limited by $T_{JM}$		360	A
$V_{SD}$	$I_F = 25\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1	0.85	1.00	V
$t_{rr}$	$I_F = 45\text{A}$ , $V_{GS} = 0\text{V}$ , $-di/dt = 100\text{A}/\mu\text{s}$ , $V_R = 27\text{V}$	37	ns	
$I_{RM}$		2.2	A	
$Q_{RM}$		40	nC	

Notes: 1. Pulse test,  $t \leq 300\mu\text{s}$ ; duty cycle,  $d \leq 2\%$ .  
 2. On through-hole packages,  $R_{DS(on)}$  Kelvin test contact location must be 5mm or less from the package body.

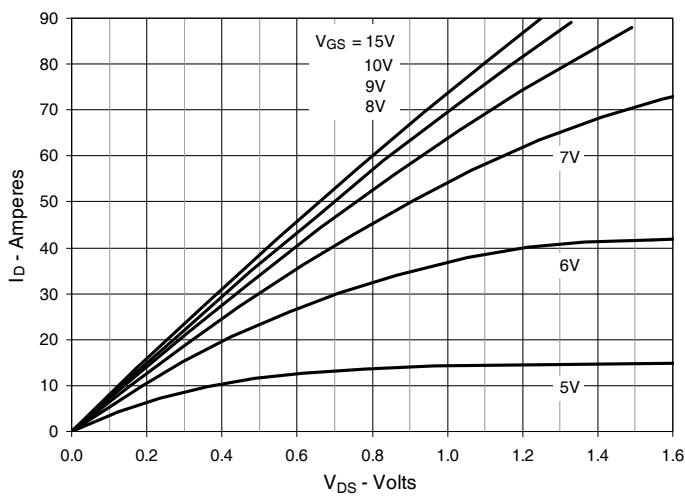
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$**



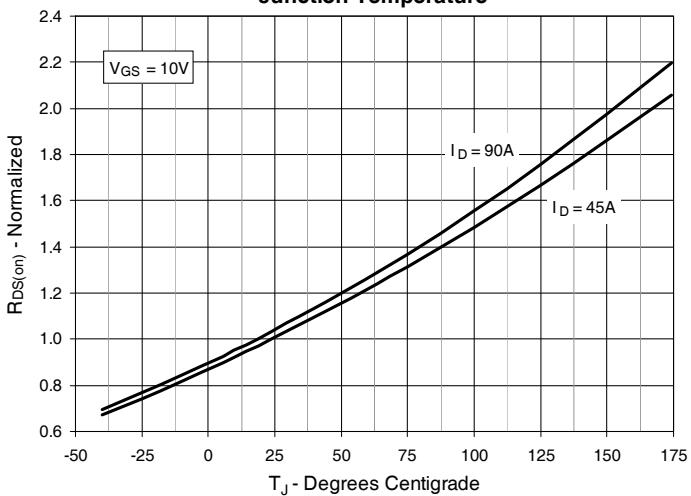
**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$**



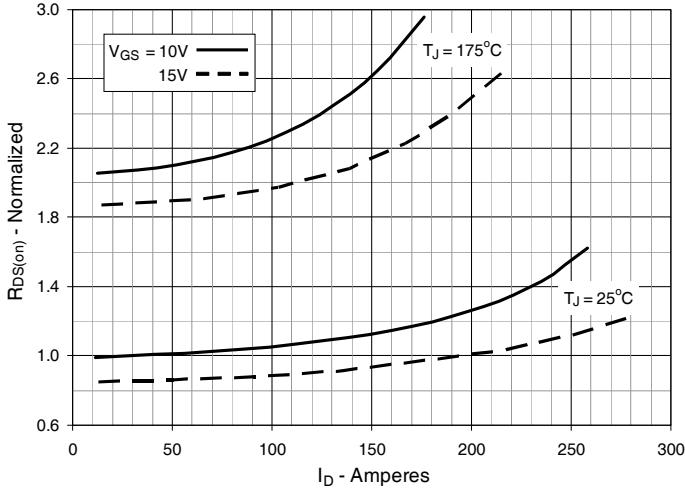
**Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$**



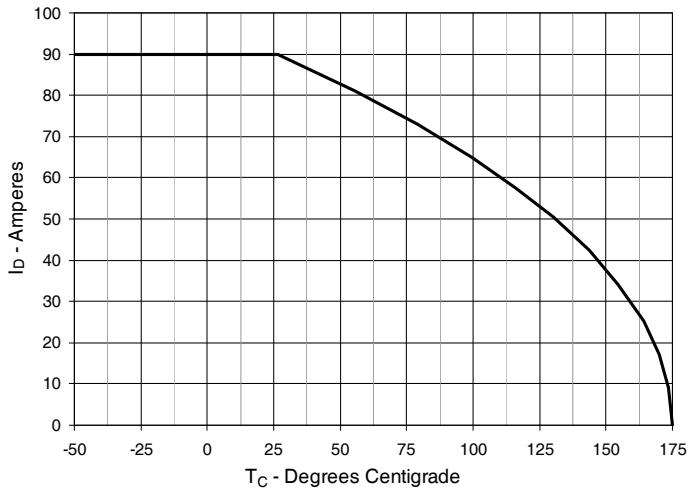
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 45\text{A}$  Value vs. Junction Temperature**

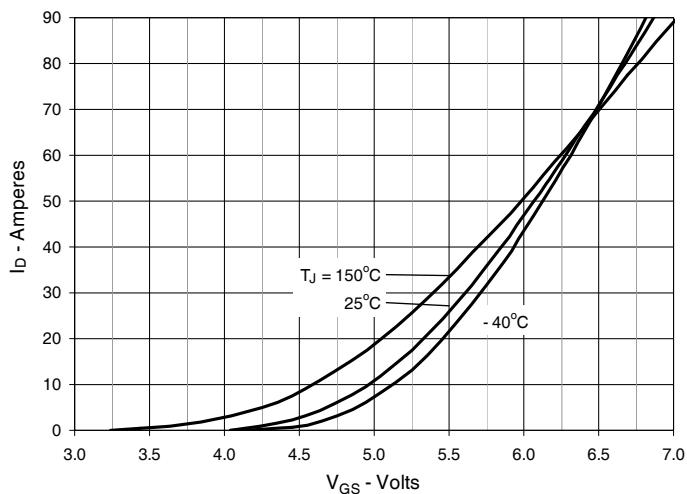
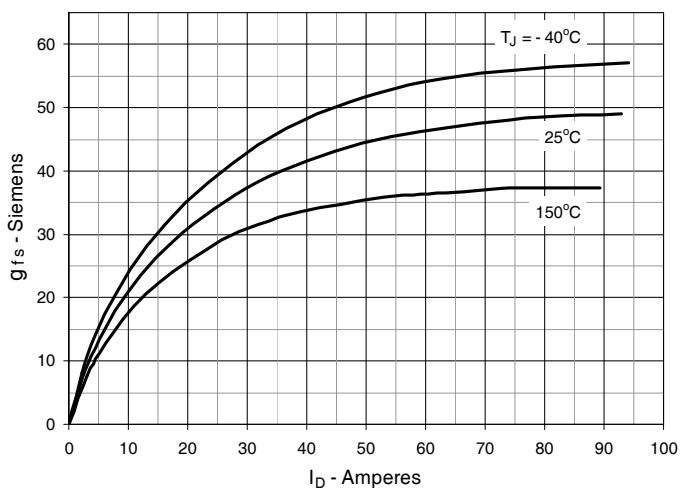
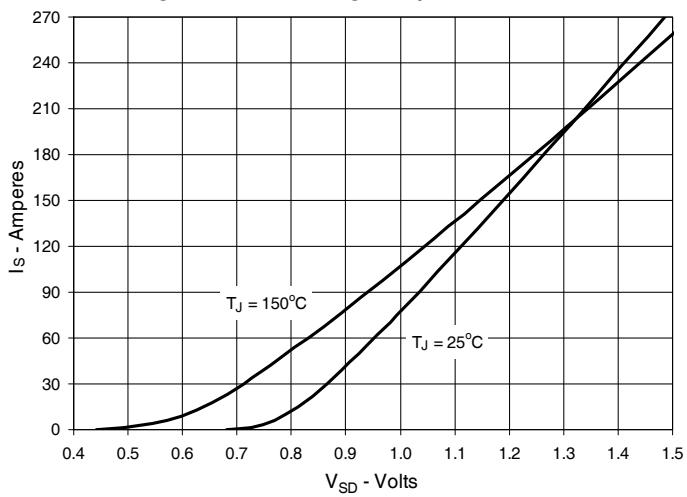
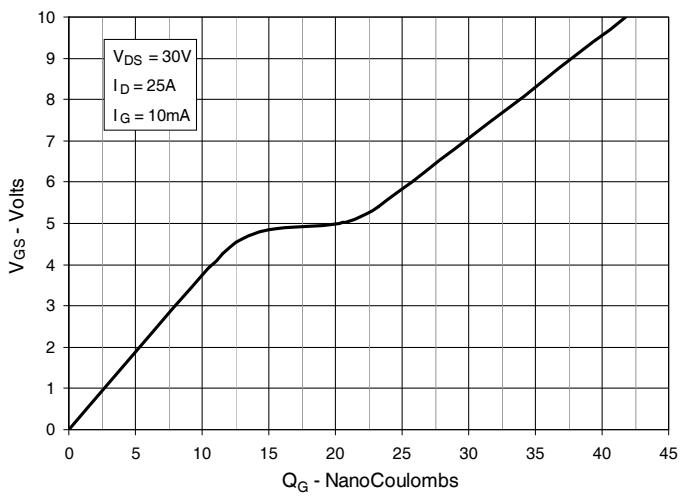
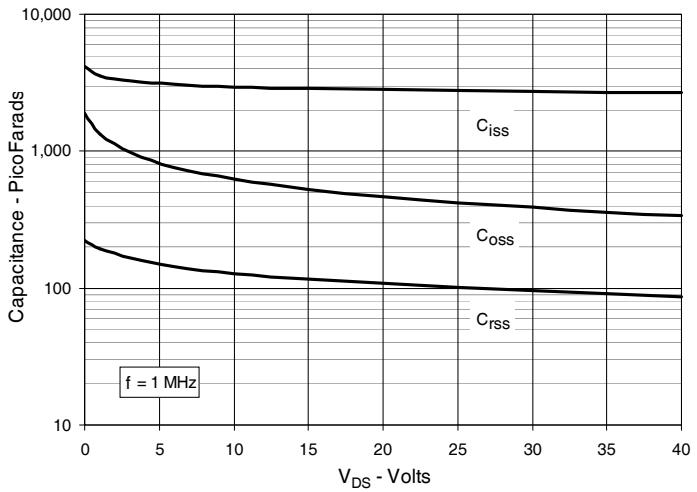
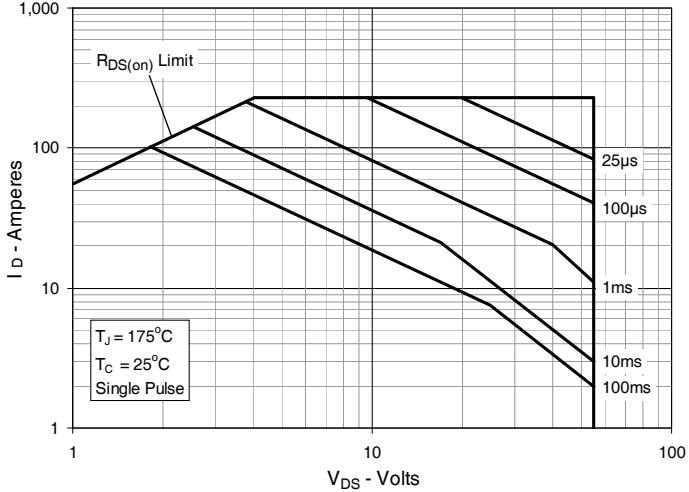


**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 45\text{A}$  Value vs. Drain Current**

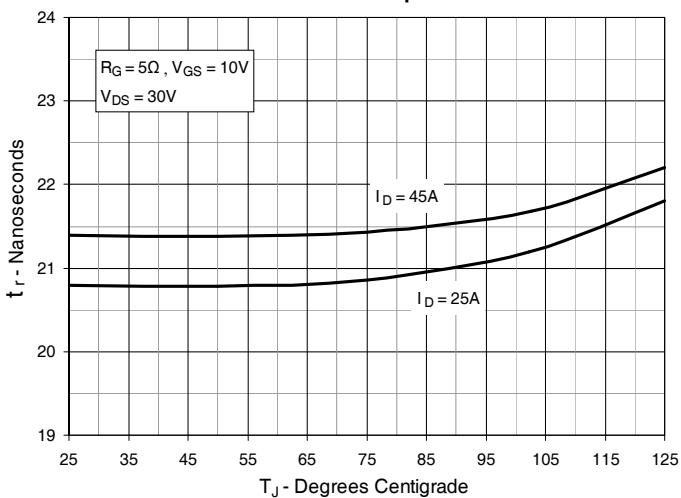


**Fig. 6. Drain Current vs. Case Temperature**

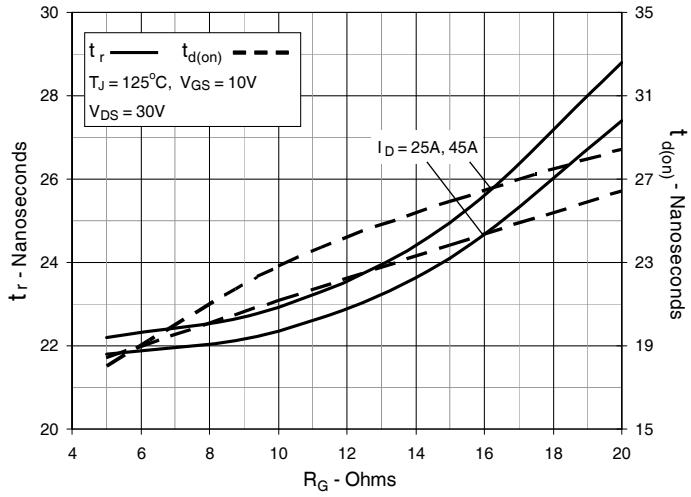


**Fig. 7. Input Admittance**

**Fig. 8. Transconductance**

**Fig. 9. Forward Voltage Drop of Intrinsic Diode**

**Fig. 10. Gate Charge**

**Fig. 11. Capacitance**

**Fig. 12. Forward-Bias Safe Operating Area**


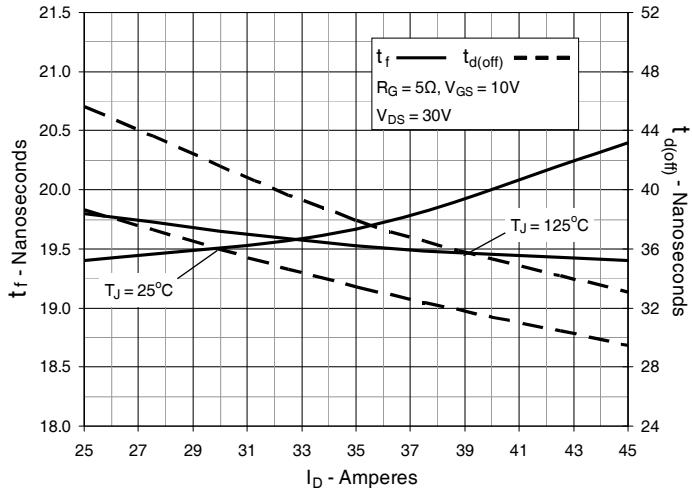
**Fig. 13. Resistive Turn-on Rise Time vs.  
Junction Temperature**



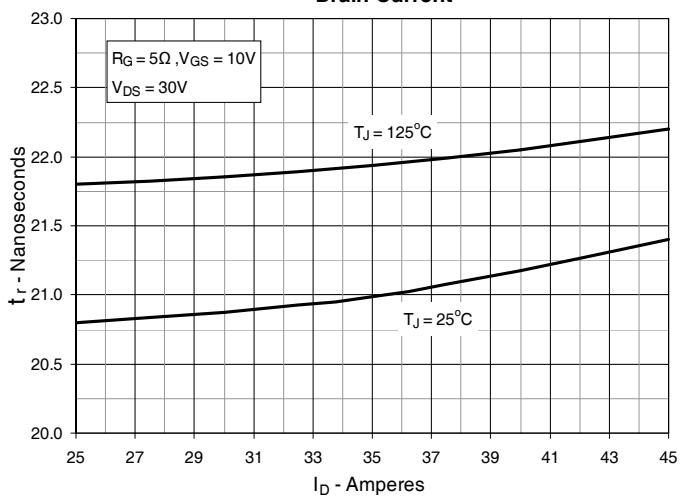
**Fig. 15. Resistive Turn-on Switching Times vs.  
Gate Resistance**



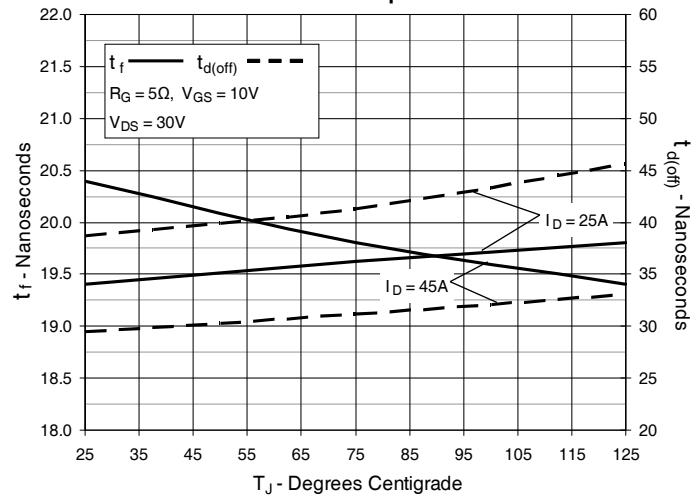
**Fig. 17. Resistive Turn-off Switching Times vs.  
Drain Current**



**Fig. 14. Resistive Turn-on Rise Time vs.  
Drain Current**



**Fig. 16. Resistive Turn-off Switching Times vs.  
Junction Temperature**



**Fig. 18. Resistive Turn-off Switching Times vs.  
Gate Resistance**

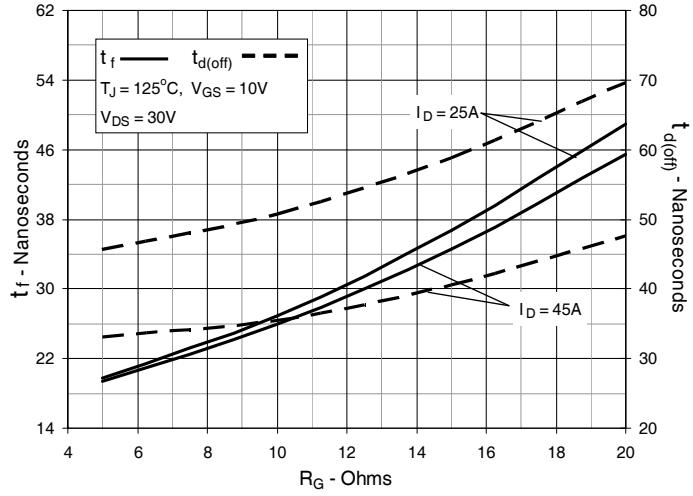
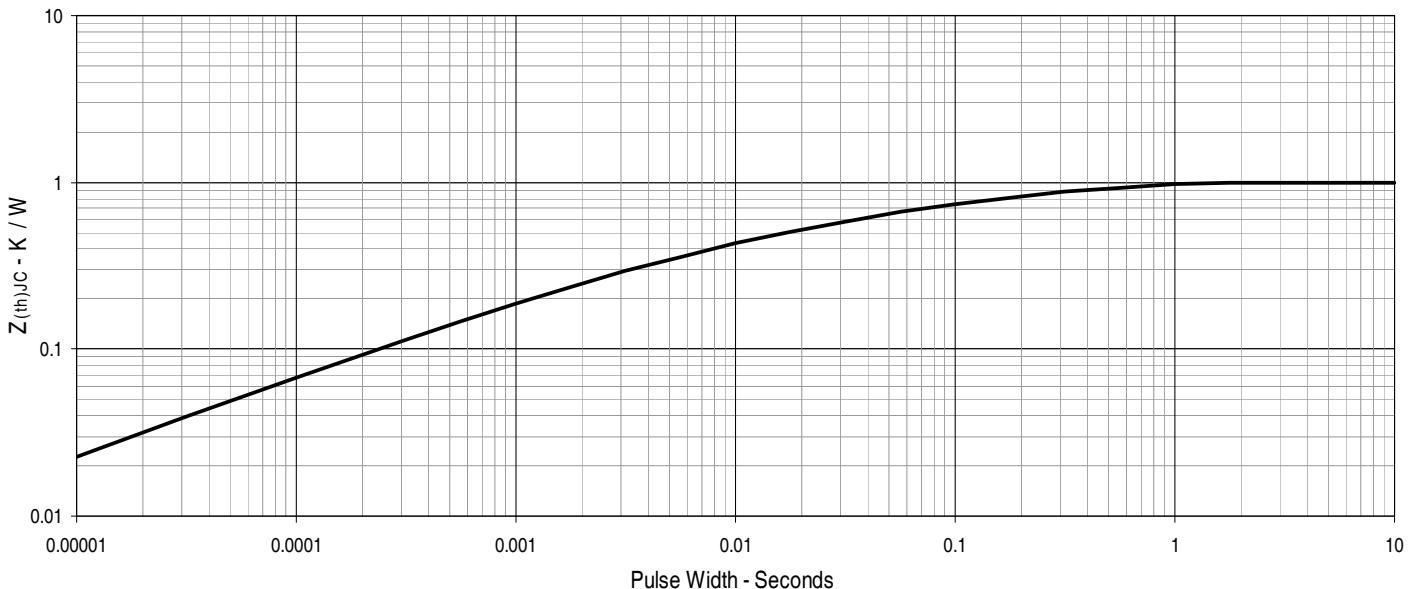
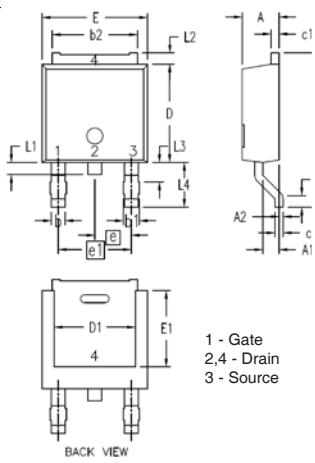
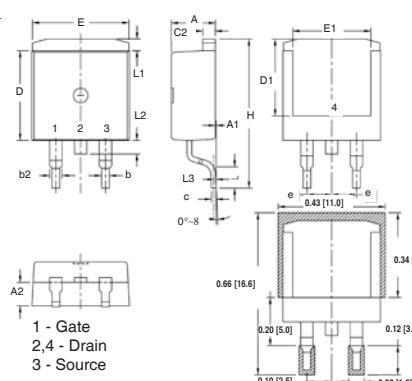


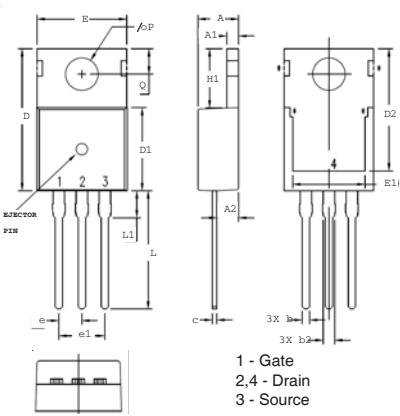
Fig. 19. Maximum Transient Thermal Impedance

**TO-252 Outline**

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.086	.094	2.19	2.38
A1	.035	.045	0.89	1.14
A2	0	.004	0	0.10
b	.025	.035	0.64	0.89
b1	.030	.045	0.76	1.14
b2	.205	.215	5.21	5.46
c	.018	.023	0.46	0.58
c1	.018	.023	0.46	0.58
D	.235	.245	5.97	6.22
D1	.170	.205	4.32	5.21
E	.250	.265	6.35	6.73
E1	.170	.205	4.32	5.21
e	.090 BSC		2.28 BSC	
e1	.180 BSC		4.57 BSC	
H	.370	.410	9.40	10.42
L	.020	.040	0.51	1.02
L1	.025	.040	0.64	1.02
L2	.024	.036	0.60	0.90
L3	.045	.060	1.15	1.52
L4	.100	.115	2.54	2.92

**TO-263 Outline**

SYM	INCHES		MILLIMETER	
	MIN	MAX	MIN	MAX
A	.170	.185	4.30	4.70
A1	.000	.008	0.00	0.20
A2	.091	.098	2.30	2.50
b	.028	.035	0.70	0.90
b2	.046	.060	1.18	1.52
C	.018	.024	0.45	0.60
C2	.049	.060	1.25	1.52
D	.340	.370	8.63	9.40
D1	.300	.327	7.62	8.30
E	.380	.410	9.65	10.41
E1	.270	.330	6.86	8.38
(e)	.100 BSC		2.54 BSC	
H	.580	.620	14.73	15.75
L	.075	.105	1.91	2.67
L1	.039	.060	1.00	1.52
L2	—	.070	—	1.77
(L3)	.010 BSC		0.254 BSC	

**TO-220 Outline**

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
b	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
c	.014	.026	0.35	0.65
D	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
e	.100 BSC		2.54 BSC	
e1	.200 BSC		5.08 BSC	
H1	.244	.268	6.20	6.80
L	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØP	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.